1-Bit Dual-Supply Non-Inverting Level Translator

The NLSV1T34 is a 1-bit configurable dual-supply voltage level translator. The input An and output Bn ports are designed to track two different power supply rails, V_{CCA} and V_{CCB} respectively. Both supply rails are configurable from 0.9 V to 4.5 V allowing universal low-voltage translation from the input A_n to the output B_n port.

Features

- Wide V_{CCA} and V_{CCB} Operating Range: 0.9 V to 4.5 V
- High-Speed w/ Balanced Propagation Delay
- Inputs and Outputs have OVT Protection to 4.5 V
- Non-preferential V_{CCA} and V_{CCB} Sequencing
- Power-Off Protection
- Power-Off High Impedance Inputs and Outputs
- Ultra–Small Packaging: 1.45 mm x 1.0 mm ULLGA6
 - 2.0 mm x 2.1 mm SC-88A 1.2 mm x 1.0 mm UDFN6 1.45 mm x 1.0 mm UDFN6
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

Typical Applications

• Mobile Phones, PDAs, Other Portable Devices

Important Information

• ESD Protection for All Pins: HBM (Human Body Model) > 3000 V

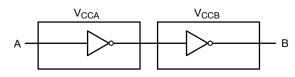


Figure 1. Logic Diagram



ON Semiconductor®

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			ARKING Agrams
1	UDFN6 MU SUFF CASE 517/		Ω M ●
	UDFN6 MU SUFF CASE 517/		● ^{A M}
1	ULLGA6 MX1 SUFF CASE 613/	'IX	QM o
1	SC-88A (SOT-353/SC DF SUFFI CASE 419	C–70) X	5 □ □ ≤ QM• ₀ • 1 □ □ □
Date Coo	Q, A = Device M = Date C = Pb-Fri e: Microdot may b de orientation an ig upon manufac	Code ee Packag oe in either d/or positio	location) on may vary
	PIN ASSIG	NMENT	
V _{CCA} 1 A 2 GND 3	6 V _{ССВ} V 5 NC 4 B G	CCA 1 A 2 IND 3	5 V _{CCB}
	6/UDFN6 view)		-88A View)

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

PIN ASSIGNMENT

PIN	FUNCTION
V _{CCA}	Input Port DC Power Supply
V _{CCB}	Output Port DC Power Supply
GND	Ground
А	Input Port
В	Output Port

TRUTH TABLE

INPUTS	OUTPUTS
А	В
L	L
Н	Н

MAXIMUM RATINGS

Symbol	Rating		Value	Condition	Unit
V _{CCA} , V _{CCB}	DC Supply Voltage		-0.5 to +5.5		V
VI	DC Input Voltage	А	-0.5 to +5.5		V
Vo	DC Output Voltage (Power Down)	В	-0.5 to +5.5	$V_{CCA} = V_{CCB} = 0$	V
	(Active Mode)	В	-0.5 to +5.5		V
I _{IK}	DC Input Diode Current		-20	V _I < GND	mA
I _{ОК}	DC Output Diode Current		-50	V _O < GND	mA
Ι _Ο	DC Output Source/Sink Current		±50		mA
I _{CCA} , I _{CCB}	DC Supply Current Per Supply Pin		±100		mA
I _{GND}	DC Ground Current per Ground Pin		±100		mA
T _{STG}	Storage Temperature		–65 to +150		°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V_{CCA}, V_{CCB}	Positive DC Supply Voltage		0.9	4.5	V
VI	Bus Input Voltage		GND	4.5	V
V _{IO}	Bus Output Voltage (Power Down Mode)	В	GND	4.5	V
	(Active Mode)	В	GND	V _{CCB}	V
T _A	Operating Temperature Range		-40	+85	°C
Δt / ΔV	Input Transition Rise or Rate V _I , from 30% to 70% of V _{CC} ; V _{CC} = 3.3 V ± 0.3 V		0	10	nS

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

					-40°C te	⊳ +85°C	
Symbol	Parameter	Test Conditions	V _{CCA} (V)	V _{CCB} (V)	Min	Max	Uni
VIH	Input HIGH Voltage		3.6 – 4.5	0.9 - 4.5	2.2	-	V
			2.7 – 3.6		2.0	-	1
			2.3 – 2.7		1.6	-	1
			1.4 – 2.3		0.65 * V _{CCA}	-	1
			0.9 – 1.4		0.9 * V _{CCA}	-	1
V _{IL}	Input LOW Voltage		3.6 - 4.5	0.9 - 4.5	-	0.8	V
			2.7 – 3.6		-	0.8	1
			2.3 – 2.7		-	0.7	1
			1.4 – 2.3		-	0.35 * V _{CCA}	1
			0.9 – 1.4		-	0.1 * V _{CCA}	1
V _{OH}	Output HIGH Voltage	I _{OH} = -100 μA; V _I = V _{IH}	0.9 - 4.5	0.9 – 4.5	V _{CCB} - 0.2	-	V
		I_{OH} = -0.5 mA; V_I = V_{IH}	0.9	0.9	0.75 * V _{CCB}	-	1
		$I_{OH} = -2 \text{ mA}; \text{ V}_{I} = \text{V}_{IH}$	1.4	1.4	1.05	-	1
		$I_{OH} = -6 \text{ mA}; \text{ V}_{I} = \text{V}_{IH}$	1.65	1.65	1.25	-	1
			2.3	2.3	2.0	-	1
		$I_{OH} = -12 \text{ mA}; \text{ V}_{I} = \text{V}_{IH}$	2.3	2.3	1.8	-	1
			2.7	2.7	2.2	-	1
		I _{OH} = -18 mA; V _I = V _{IH}	2.3	2.3	1.7	-	1
			3.0	3.0	2.4	-	1
		I_{OH} = -24 mA; V_{I} = V_{IH}	3.0	3.0	2.2	-	1
V _{OL}	Output LOW Voltage	I _{OL} = 100 μA; V _I = V _{IL}	0.9 - 4.5	0.9 – 4.5	-	0.2	V
		I_{OL} = 0.5 mA; V_I = V_{IH}	1.1	1.1	-	0.3	1
		$I_{OL} = 2 \text{ mA}; V_I = V_{IH}$	1.4	1.4	-	0.35	1
		$I_{OL} = 6 \text{ mA}; V_I = V_{IL}$	1.65	1.65	-	0.3	1
		I_{OL} = 12 mA; $V_I = V_{IL}$	2.3	2.3	-	0.4	1
			2.7	2.7	-	0.4	1
		I_{OL} = 18 mA; V_I = V_{IL}	2.3	2.3	-	0.6	1
			3.0	3.0	-	0.4	1
		I_{OL} = 24 mA; V_I = V_{IL}	3.0	3.0	-	0.55	1
I _I	Input Leakage Current	$V_I = V_{CCA}$ or GND	0.9 - 4.5	0.9 - 4.5	-1.0	1.0	μA
I _{CCA}	Quiescent Supply Current		0.9 - 4.5	0.9 – 4.5	-	2.0	μA
I _{CCB}	Quiescent Supply Current		0.9 - 4.5	0.9 – 4.5	-	2.0	μA
_{CA} + I _{CCB}	Quiescent Supply Current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CCA} \text{ or } GND; \\ I_{O} = 0, \ V_{CCA} = V_{CCB} \end{array}$	0.9 - 4.5	0.9 – 4.5	-	4.0	μA
I _{OFF}	Power OFF Leakage Current	V ₁ = 4.5 V	0	0	-	5.0	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TOTAL STATIC POWER CONSUMPTION (I_{CCA} + I_{CCB})

					–40°C t	o +85°C					
					Vcc	_в (V)					
	4	.5	3	.3	2	.8	1	.8	0	.9	
V _{CCA} (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
4.5		2		2		2		2		< 1.5	μΑ
3.3		2		2		2		2		< 1.5	μA
2.8		< 2		< 1		< 1		< 0.5		< 0.5	μΑ
1.8		< 1		< 1		< 0.5		< 0.5		< 0.5	μA
0.9		< 0.5		< 0.5		< 0.5		< 0.5		< 0.5	μA

NOTE: Connect ground before applying supply voltage V_{CCA} or V_{CCB}. This device is designed with the feature that the power-up sequence of V_{CCA} and V_{CCB} will not damage the IC.

AC ELECTRICAL CHARACTERISTICS

							–40°C t	o +85°C					
				V _{CCB} (V)									
			4	.5	3	.3	2	.8	1	.8	1	.2	
Symbol	Parameter	V _{CCA} (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t _{PLH} ,	Propagation	4.5		1.6		1.8		2.0		2.1		2.3	nS
t _{PHL} (Note 1)	Delay,	3.3		1.7		1.9		2.1		2.3		2.6	l
(1010-1)	A to B	2.8		1.9		2.1		2.3		2.5		2.8	
		1.8		2.1		2.4		2.5		2.7		3.0	l
		1.2		2.4		2.7		2.8		3.0		3.3	

1. Propagation delays defined per Figure 2.

CAPACITANCE

Symbol	Parameter	Test Conditions	Typ (Note 2)	Unit
C _{I/O}	I/O Pin Input Capacitance	V_{CCA} = V_{CCB} = 3.3 V, V_{I} = 0 V or $V_{CCA/B}$	5.0	pF
C _{PD}	Power Dissipation Capacitance	V_{CCA} = V_{CCB} = 3.3 V, V_{I} = 0 V or V_{CCA},f = 10 MHz	5.0	pF

2. Typical values are at $T_A = +25^{\circ}C$. 3. C_{PD} is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from: $I_{CC(operating)} \cong C_{PD} \times V_{CC} \times f_{IN}$ where $I_{CC} = I_{CCA} + I_{CCB}$.

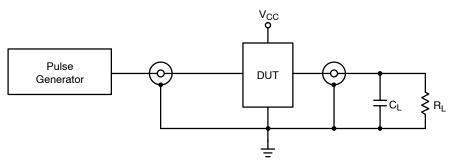
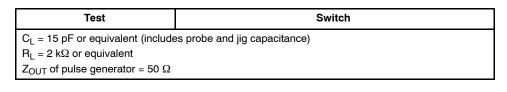
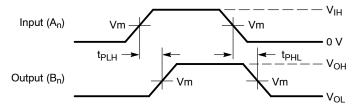


Figure 2. AC (Propagation Delay) Test Circuit





Waveform 1 – Propagation Delays

 t_{R} = t_{F} = 2.0 ns, 10% to 90%; f = 1 MHz; t_{W} = 500 ns

Figure 3. AC (Propagation Delay) Test Circuit Waveforms

	V _{cc}
Symbol	0.9 V – 4.5 V
V _{mA}	V _{CCA} /2
V _{mB}	V _{CCB} /2

ORDERING INFORMATION

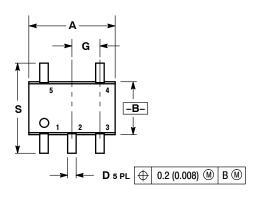
Device	Package	Shipping [†]
NLSV1T34MUTBG	UDFN6, 1.2 x 1.0, 0.4P (Pb–Free)	3000 / Tape & Reel
NLSV1T34AMUTCG	UDFN6, 1.45 x 1.0, 0.5P (Pb–Free)	3000 / Tape & Reel
NLSV1T34AMX1TCG	ULLGA6 (Pb-Free)	3000 / Tape & Reel
NLSV1T34DFT2G	SC-88A	3000 / Tape & Reel
NLVSV1T34DFT2G*	(Pb-Free)	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

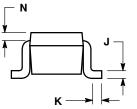
PACKAGE DIMENSIONS

SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE L



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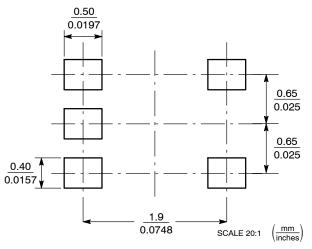


NOTES:

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02. 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIM	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
С	0.031	0.043	0.80	1.10	
D	0.004	0.012	0.10	0.30	
G	0.026	BSC	0.65 BSC		
Н		0.004		0.10	
ſ	0.004	0.010	0.10	0.25	
Κ	0.004	0.012	0.10	0.30	
Ν	0.008	REF	0.20 REF		
s	0.079	0.087	2.00	2.20	

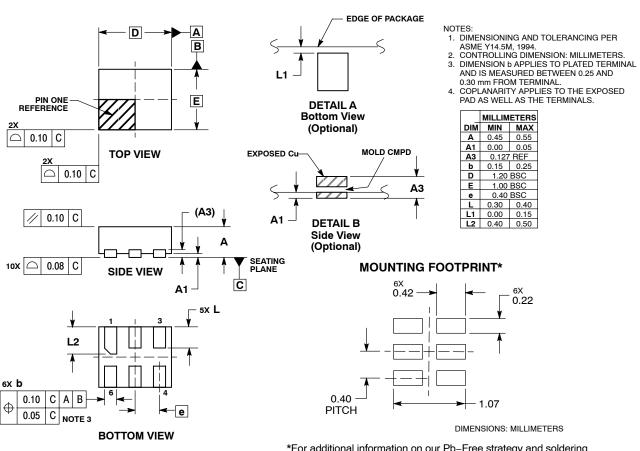
SOLDER FOOTPRINT



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

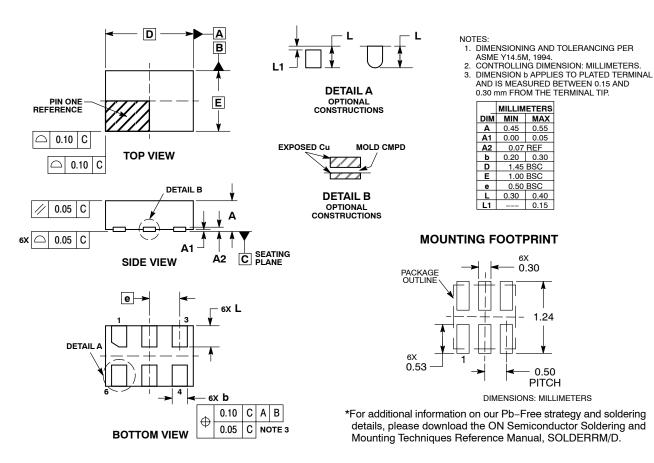
UDFN6, 1.2x1.0, 0.4P CASE 517AA ISSUE D



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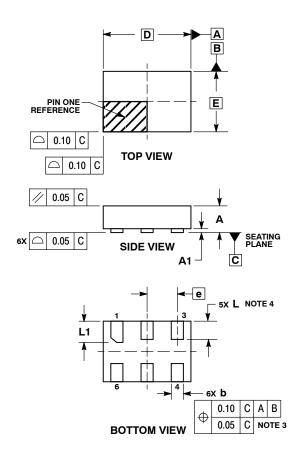
PACKAGE DIMENSIONS

UDFN6, 1.45x1.0, 0.5P CASE 517AQ ISSUE O



PACKAGE DIMENSIONS

ULLGA6 1.45x1.0, 0.5P CASE 613AF **ISSUE A**

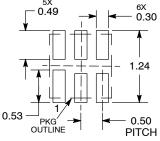


NOTES:

- DIES.
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION & APPLIES TO PLATED TERMINAL
- AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.
- A MAXIMUM OF 0.05 PULL BACK OF THE PLATED TERMINAL FROM THE EDGE OF THE PACKAGE IS ALLOWED.

	MILLIMETERS	
DIM	MIN	MAX
Α		0.40
A1	0.00	0.05
b	0.15	0.25
D	1.45 BSC	
E	1.00 BSC	
е	0.50 BSC	
L	0.25	0.35
L1	0.30	0.40

MOUNTING FOOTPRINT SOLDERMASK DEFINED*



DIMENSIONS: MILLIMETERS

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